

Bipolar Transistor

(-)50 V, (-)5 A, Low V_{CE(sat)}, (PNP)NPN Single TP/TP-FA

2SB1203/2SD1803

Features

- Low Collector-to-Emitter Saturation Voltage
- Excellent Linearity of hFE
- Small and Slim Package Making It Easy to Make 2SB1203/2SD1803-Applied Sets Smaller
- High Current and High f_T
- Fast Switching Speed

Applications

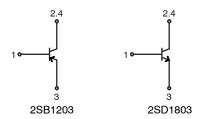
• Relay Drivers, High-Speed Inverters, Converters, and Other General High-Current Switching Applications

ABSOLUTE MAXIMUM RATINGS (at Ta = 25°C)

Symbol	Parameter	Condition	Rating	Unit
V _{CBO}	Collector-to-Base Voltage		(-)60	V
V _{CEO}	Collector-to-Emitter Voltage		(-)50	V
V _{EBO}	Emitter-to-Base Voltage		(-)6	V
I _C	Collector Current		(–)5	Α
I _{CP}	Collector Current (Pulse)		(–)8	Α
P _C	Collector Dissipation		1	W
		Tc = 25°C	20	W
Tj	Junction Temperature		150	°C
Tstg	Storage Temperature		–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELETRICAL CONNECTION



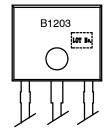


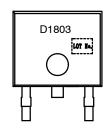


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MARKING DIAGRAM





ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 6.

ELECTRICAL CHARACTERISTICS (at T_A = 25°C)

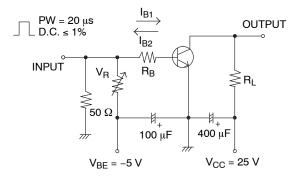
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	Collector Cutoff Current	V _{CB} = (-)40 V, I _E = 0 A			(–)1	μΑ
I _{EBO}	Emitter Cutoff Current	$V_{EB} = (-)4 \text{ V, } I_{C} = 0 \text{ A}$			(–)1	μΑ
h _{FE} 1	DC Current Gain	V _{CE} = (-)2 V, I _C = (-)0.5 A	70 (Note 1)		400 (Note 1)	
h _{FE} 2		V _{CE} = (-)2 V, I _C = (-)4 A	35			
f _T	Gain-Bandwidth Product	V _{CE} = (-)5 V, I _C = (-)1 A		(130)180		MHz
Cob	Output Capacitance	V _{CB} = (-)10 V, f = 1 MHz		(60)40		pF
V _{CE(sat)}	Collector-to-Emitter Saturation Voltage	I _C = (-)3 A, I _B = (-)0.15 A		(-280)220	(-550)400	mV
V _{BE(sat)}	Base-to-Emitter Saturation Voltage	I _C = (-)3 A, I _B = (-)0.15 A		(-)0.95	(–)1.3	V
V _{(BR)CBO}	Collector-to-Base Breakdown Voltage	I _C = (-)10 μA, I _E = 0 A	(-)60			V
V _{(BR)CEO}	Collector-to-Emitter Breakdown Voltage	$I_C = (-)1$ mA, $R_{BE} = \infty$	(-)50			V
V _{(BR)EBO}	Emitter-to-Base Breakdown Voltage	I _E = (-)10 μA, I _C = 0 A	(-)6			V
t _{on}	Turn-On Time	See Specified Test Circuit		(50)50		ns
t _{stg}	Storage Time			(450)500		ns
t _f	Fall Time			(20)20		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. The 2SB1203/2SD1803 are classified by 0.5 A h_{FE} as follows:

Rank	Q	R	S	T
h _{FE}	70 to 140	100 to 200	140 to 280	200 to 400

Switching Time Test Circuit



 I_C = 10 I_{B1} = -10 I_{B2} = 2 A For PNP, the polarity is reversed.

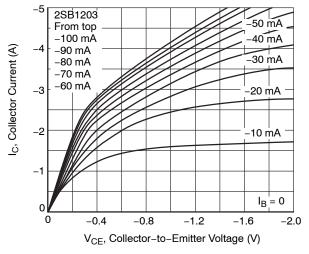


Figure 1. I_C - V_{CE}

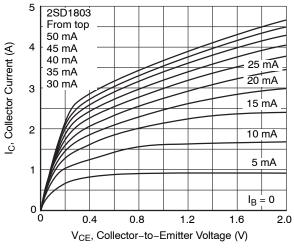


Figure 2. I_C – V_{CE}

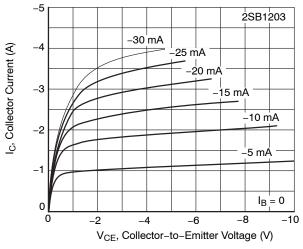


Figure 3. I_C - V_{CE}

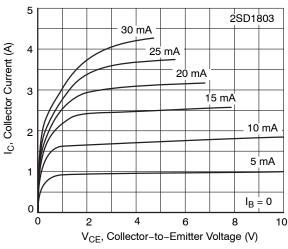


Figure 4. I_C - V_{CE}

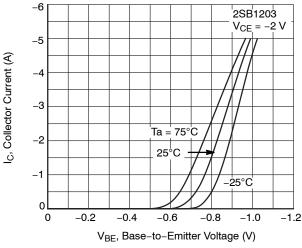


Figure 5. I_C - V_{BE}

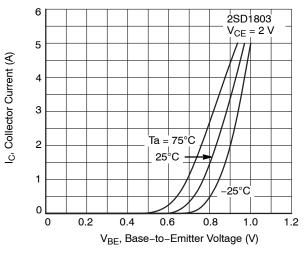


Figure 6. I_C - V_{BE}

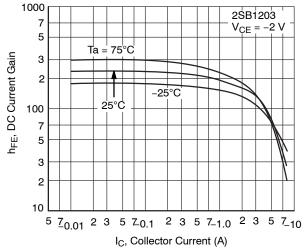


Figure 7. h_{FE} _ I_C

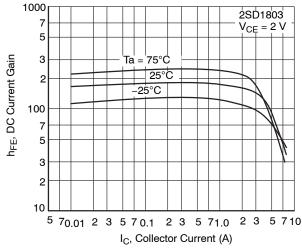


Figure 8. h_{FE} _ I_C

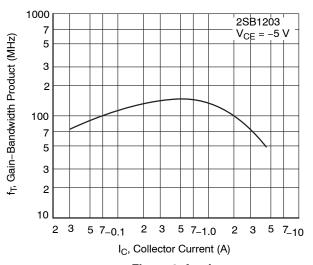


Figure 9. f_T - I_C

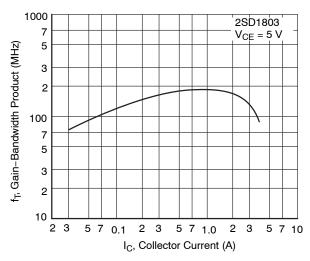


Figure 10. f_T - I_C

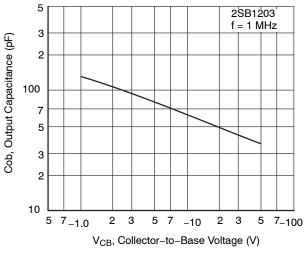


Figure 11. Cob - V_{CB}

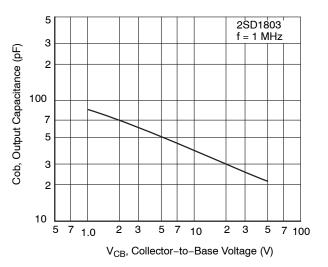


Figure 12. Cob - V_{CB}

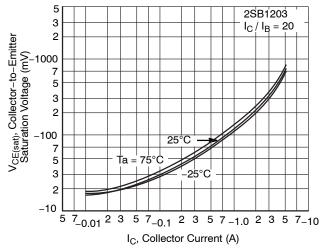


Figure 13. V_{CE(sat)} _ I_C

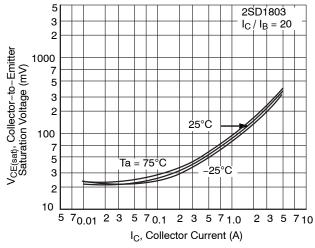


Figure 14. V_{CE(sat)} _ I_C

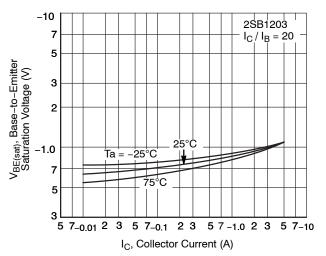


Figure 15. V_{BE(sat)} - I_C

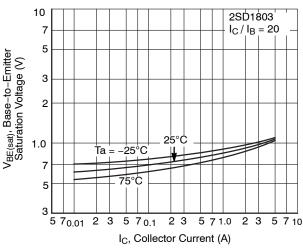


Figure 16. V_{BE(sat)} - I_C

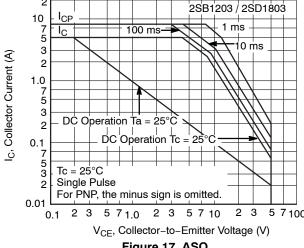


Figure 17. ASO

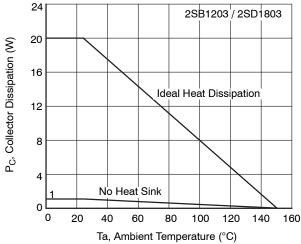


Figure 18. P_C - T_a

ORDERING INFORMATION

Device	Package	Shipping	memo
2SD1803T-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free

DISCONTINUED (Note 2)

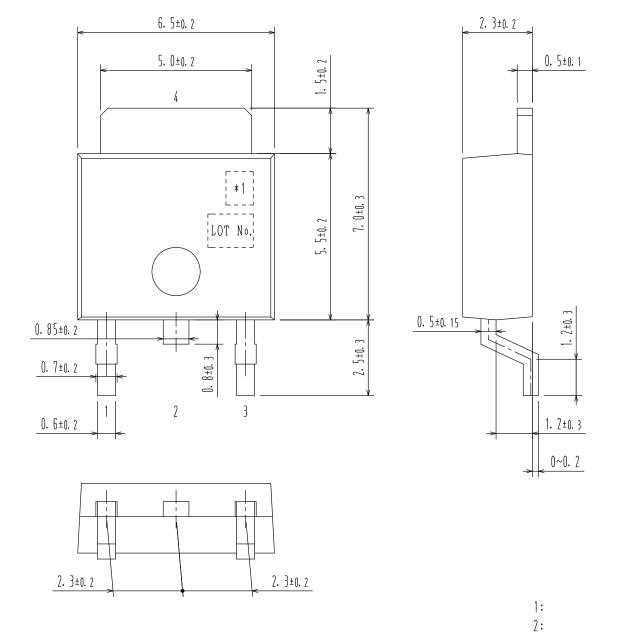
2SB1203S-E	TP	500pcs./bag	Pb Free
2SB1203S-H	TP	500pcs./bag	Pb Free and Halogen Free
2SB1203T-H	TP	500pcs./bag	Pb Free and Halogen Free
2SD1803S-H	TP	500pcs./bag	Pb Free and Halogen Free
2SD1803T-E	TP	500pcs./bag	Pb Free
2SD1803T-H	TP	500pcs./bag	Pb Free and Halogen Free
2SB1203S-TL-E	TP-FA	700pcs./bag	Pb Free
2SB1203S-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free
2SB1203T-TL-E	TP-FA	700pcs./bag	Pb Free
2SB1203T-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free
2SD1803S-TL-E	TP-FA	700pcs./bag	Pb Free
2SD1803S-TL-H	TP-FA	700pcs./bag	Pb Free and Halogen Free
2SD1803T-TL-E	TP-FA	700pcs./bag	Pb Free
2SD1803S-E	TP	500pcs./bag	Pb Free

^{2.} **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.



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DATE 30 JAN 2012



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Pin 7 is idle pin with electrical

designation only carried.

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3:
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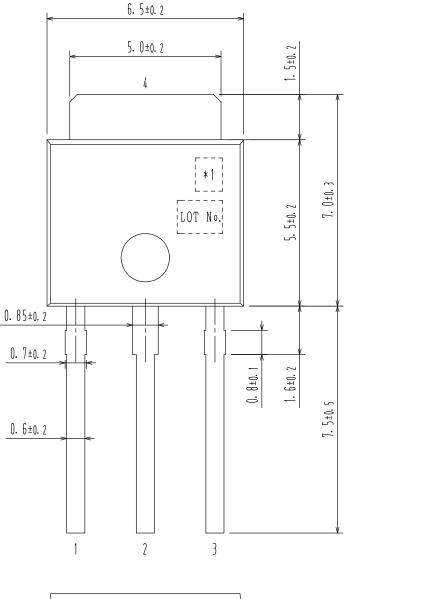
*1:Lot indication

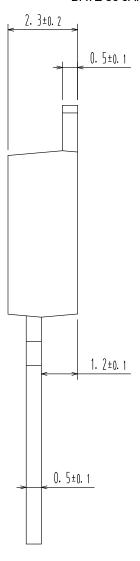


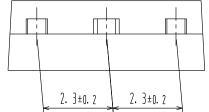


IPAK / TP CASE 369AJ ISSUE O

DATE 30 JAN 2012







		1:
		2:
		3:
*1:Lot	indication	4:

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